PerFET™ Power Transistor

FEATURES

- Excellent FOM
- AEC-Q101 Qualified
- Wettable Flank leads for Enhanced AOI
- 100% UIS and Rg tested
- 175°C Operating Junction Temperature
- RoHS Compliant
- Halogen-Free

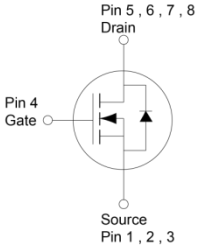
PRODUCT SUMMARY			
PARAMETER		**VALUE**	**UNIT**
V_{DS}		40	V
$R_{DS(on)}$ (max)	V_{GS} = 10V	7	mΩ
	V_{GS} = 4.5V	9.8	
Q_g	V_{GS} = 4.5V	11	nC

APPLICATIONS

- Automotive Applications
- Solenoid and Motor Drivers
- DC-DC Converters

Pb-Free RoHS COMPLIANT HALOGEN FREE

PDFN56U



Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)				
PARAMETER		**SYMBOL**	**LIMIT**	**UNIT**
Drain-Source Voltage		V_{DS}	40	V
Gate-Source Voltage		V_{GS}	±16	V
Continuous Drain Current, Silicon limited	T_C = 25°C	I_D	70	A
Continuous Drain Current (Note 1)	T_C = 25°C	I_D	54	A
	T_C = 100°C		50	
	T_A = 25°C		16	
Pulsed Drain Current (Note 2)		I_{DM}	216	A
Single Pulse Avalanche Current (Note 3)		I_{AS}	18.2	A
Single Pulse Avalanche Energy (Note 3)		E_{AS}	49.9	mJ
Total Power Dissipation	T_C = 25°C	P_D	46.8	W
	T_C = 125°C		15.6	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55 to +175	°C

THERMAL RESISTANCE			
PARAMETER	**SYMBOL**	**MAXIMUM**	**UNIT**
Thermal Resistance – Junction to Case	$R_{\Theta JC}$	2.5	°C/W
Thermal Resistance – Junction to Ambient (Note 4)	$R_{\Theta JA}$	50	°C/W

NOTE:

1. Package current limit.
2. Pulse Width ≤ 100μs.
3. L = 0.3mH, VGS = 10V, RG = 25Ω, Starting TJ = 25°C.
4. Device on a PCB FR4 with 1 in^2 (single layer, 2 oz thick) copper area for drain connection.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)						
PARAMETER	**CONDITIONS**	**SYMBOL**	**MIN**	**TYP**	**MAX**	**UNIT**
Static						
Drain-Source Breakdown Voltage	V_{GS} = 0V, I_D = 1mA	BV_{DSS}	40	--	--	V
Gate Threshold Voltage	V_{GS} = V_{DS}, I_D = 250μA	$V_{GS(TH)}$	1.4	1.8	2.2	V
Gate-Source Leakage Current	V_{GS} = ±16V, V_{DS} = 0V	I_{GSS}	--	--	±100	nA
Drain-Source Leakage Current	V_{GS} = 0V, V_{DS} = 40V	I_{DSS}	--	--	1	μA
	V_{GS} = 0V, V_{DS} = 40V T_J = 125°C		--	--	100	
Drain-Source On-State Resistance (Note 5)	V_{GS} = 10V, I_D = 27A	$R_{DS(on)}$	--	5.6	7	mΩ
	V_{GS} = 4.5V, I_D = 27A		--	7.5	9.8	
Forward Transconductance (Note 5)	V_{DS} = 10V, I_D = 7A	g_{fs}	--	60	--	S
Dynamic (Note 6)						
Total Gate Charge	V_{GS} = 4.5V, V_{DS} = 20V, I_D = 16A	Q_g	--	11	16.5	nC
Total Gate Charge	V_{GS} = 10V, V_{DS} = 20V, I_D = 16A	Q_g	--	23	34.5	
Gate-Source Charge		Q_{gs}	--	4.3	8.6	
Gate-Drain Charge		Q_{gd}	--	3.5	7	
Input Capacitance	V_{GS} = 0V, V_{DS} = 25V, f = 1.0MHz	C_{iss}	--	1446	2169	pF
Output Capacitance		C_{oss}	--	229	458	
Reverse Transfer Capacitance		C_{rss}	--	34	68	
Gate Resistance	f = 1.0MHz	R_g	--	1.4	--	Ω
Switching (Note 7)						
Turn-On Delay Time	V_{GS} = 10V, V_{DS} = 20V, I_D = 16A, R_G = 3.3Ω	$t_{d(on)}$	--	7.2	--	ns
Rise Time		t_r	--	50.8	--	
Turn-Off Delay Time		$t_{d(off)}$	--	23.2	--	
Fall Time		t_f	--	5.7	--	
Source-Drain Diode						
Diode Forward Voltage (Note 5)	V_{GS} = 0V, I_S = 27A	V_{SD}	--	--	1.1	V
Reverse Recovery Time	I_S = 16A, di/dt = 100A/μs	t_{rr}	--	32	--	ns
Reverse Recovery Charge		Q_{rr}	--	26	--	nC

Notes:

5. Pulse test: Pulse Width ≤ 300μs, duty cycle ≤ 2%.
6. Defined by design. Not subject to production test.
7. Switching time is essentially independent of operating temperature.

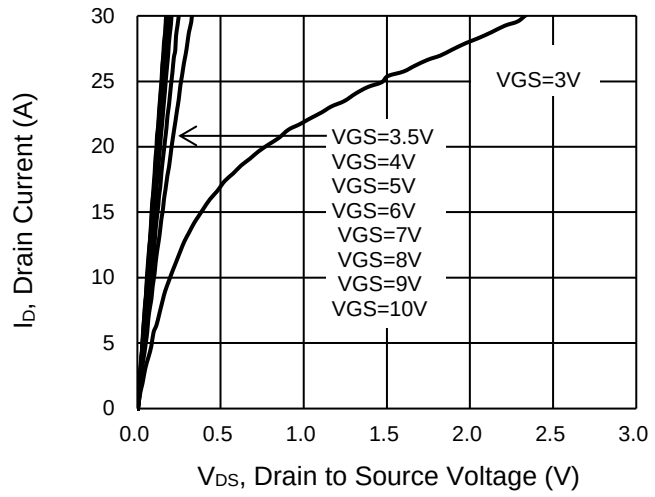
ORDERING INFORMATION

ORDERING CODE	PACKAGE	PACKING
TQM070NH04LCR RLG	PDFN56U	2,500pcs / 13” Reel

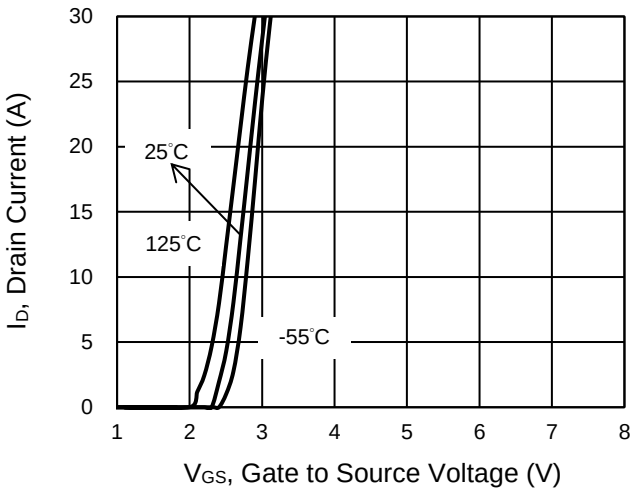
CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

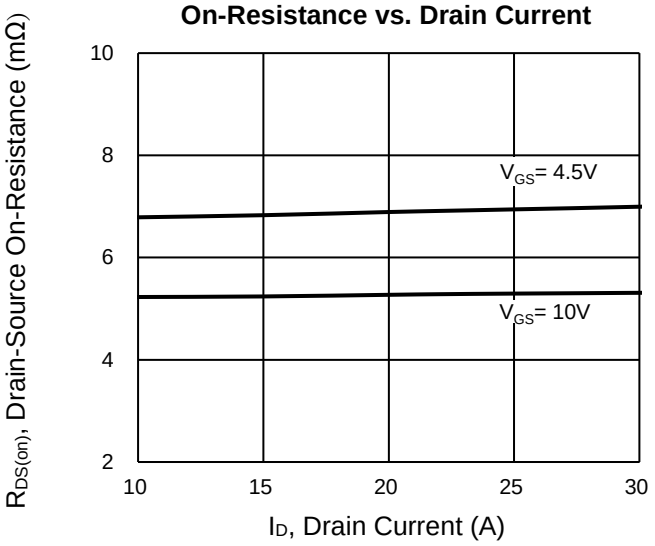
Output Characteristics



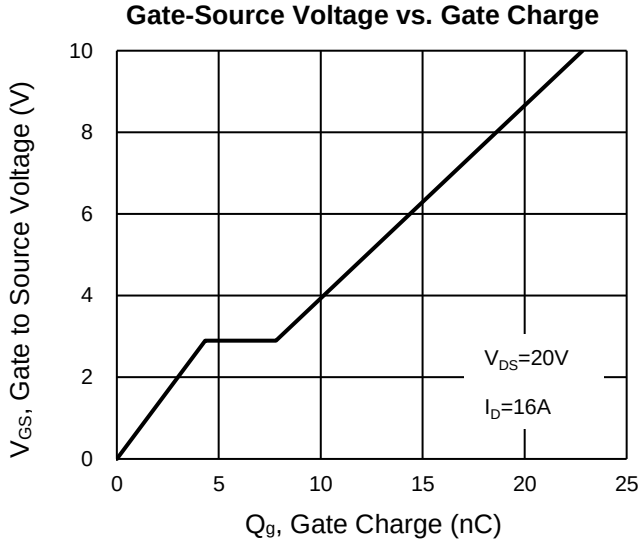
Transfer Characteristics



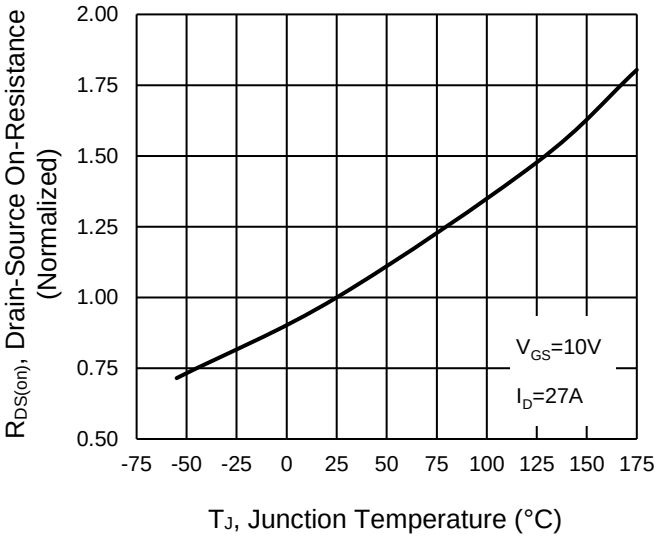
On-Resistance vs. Drain Current



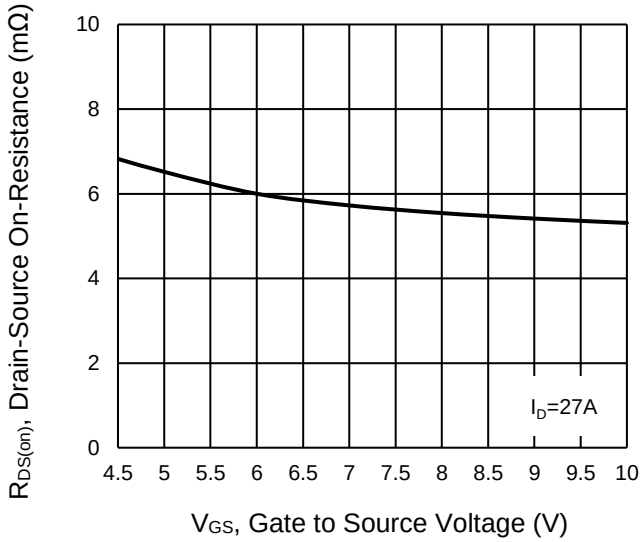
Gate-Source Voltage vs. Gate Charge



On-Resistance vs. Junction Temperature



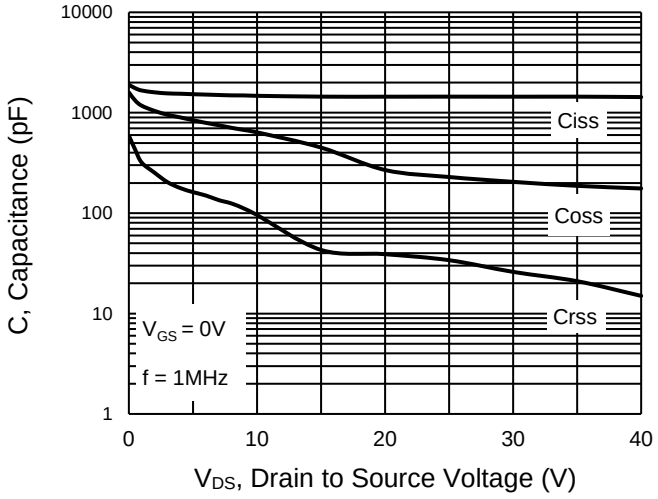
On-Resistance vs. Gate-Source Voltage



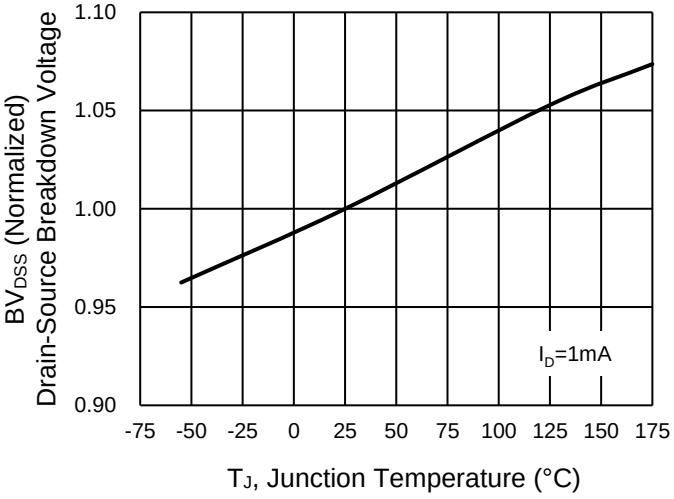
CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

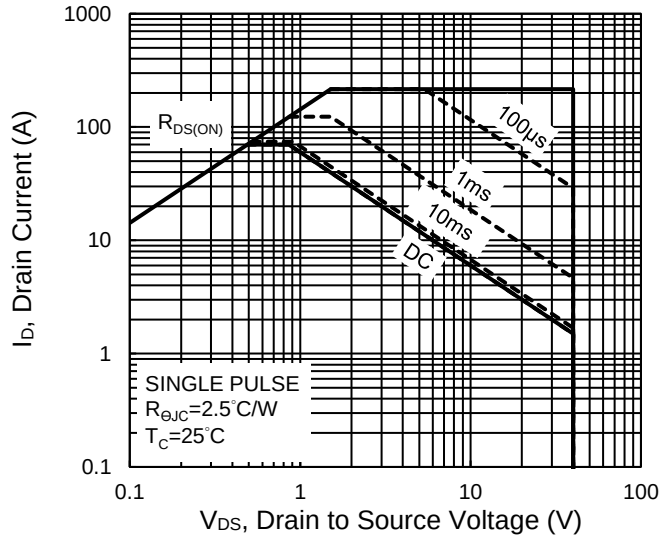
Capacitance vs. Drain-Source Voltage



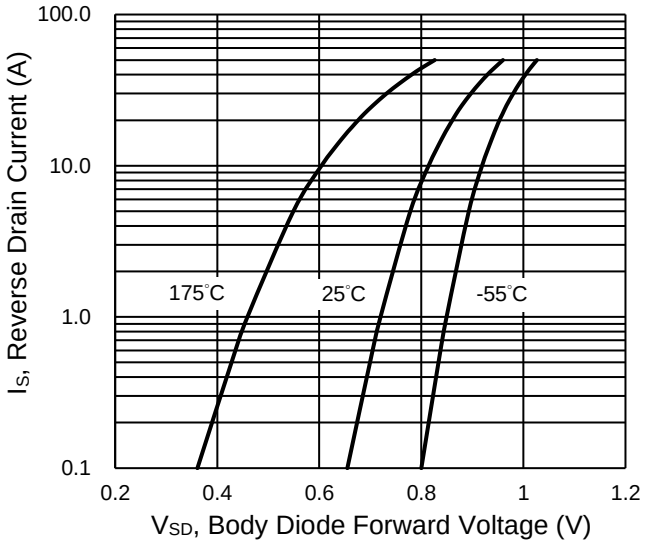
BV_{DSS} vs. Junction Temperature



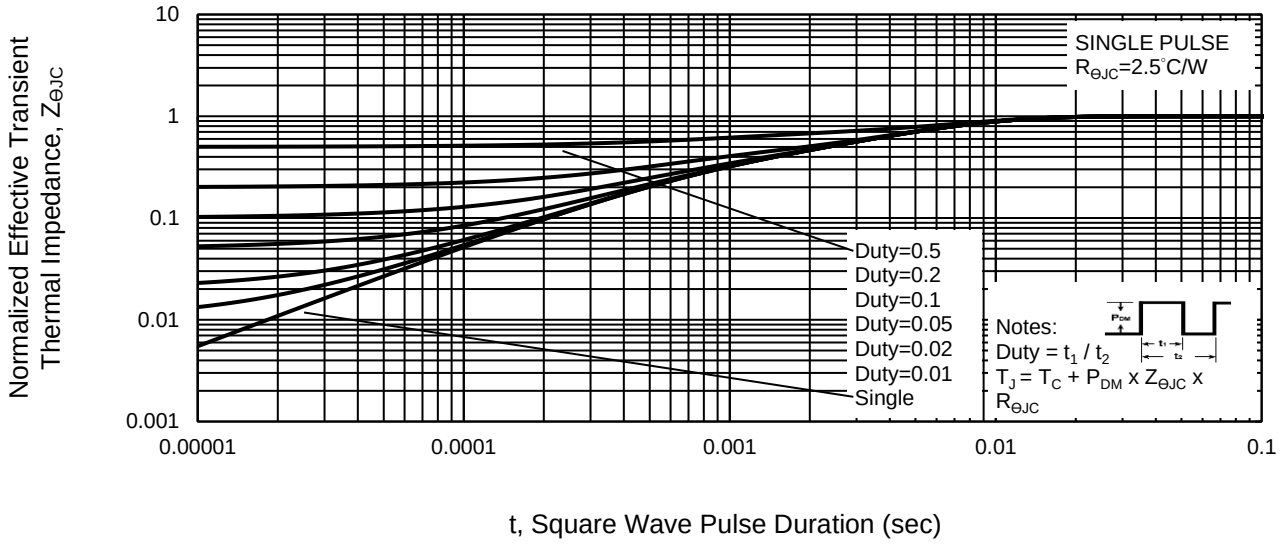
Maximum Safe Operating Area, Junction-to-Case



Source-Drain Diode Forward Current vs. Voltage



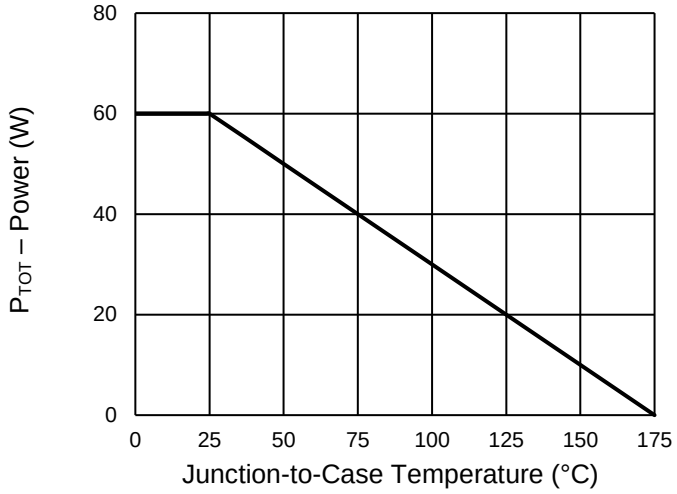
Normalized Thermal Transient Impedance, Junction-to-Case



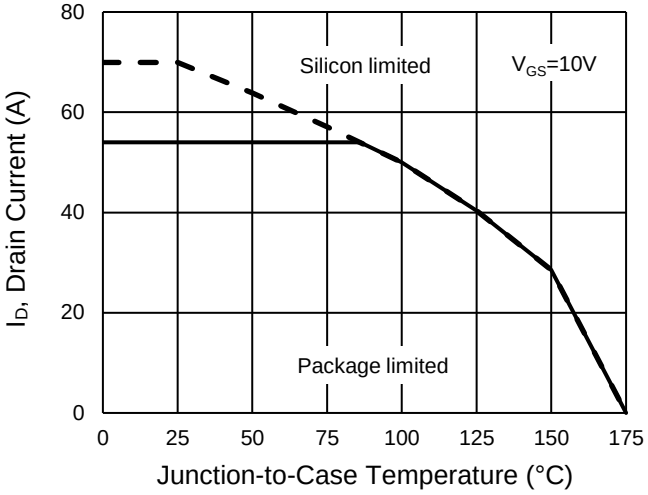
CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

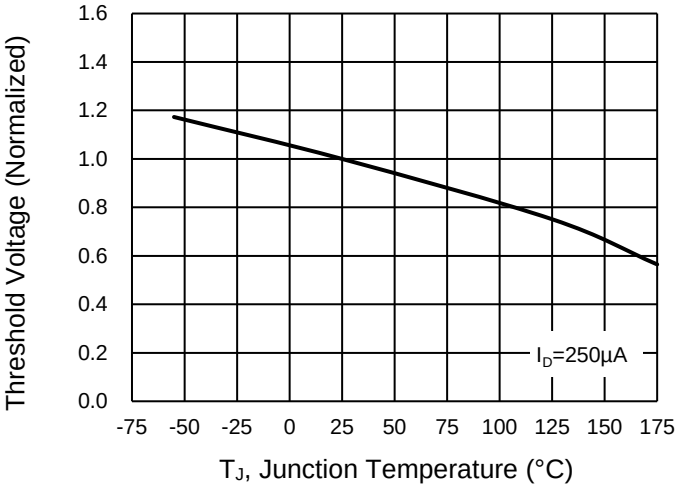
Power Dissipation



Drain Current

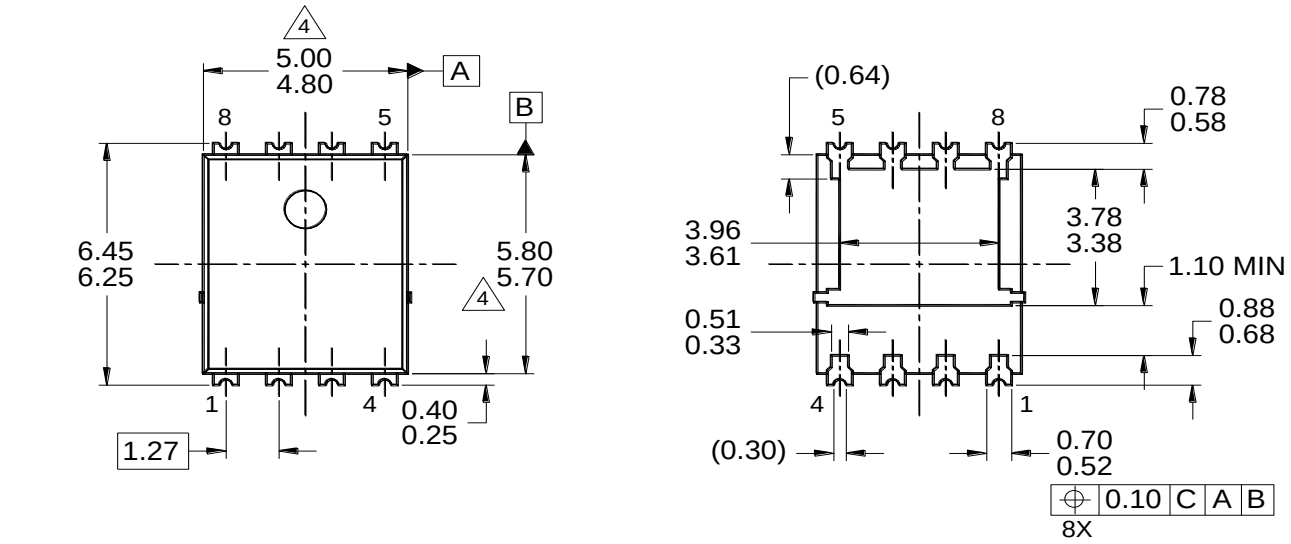


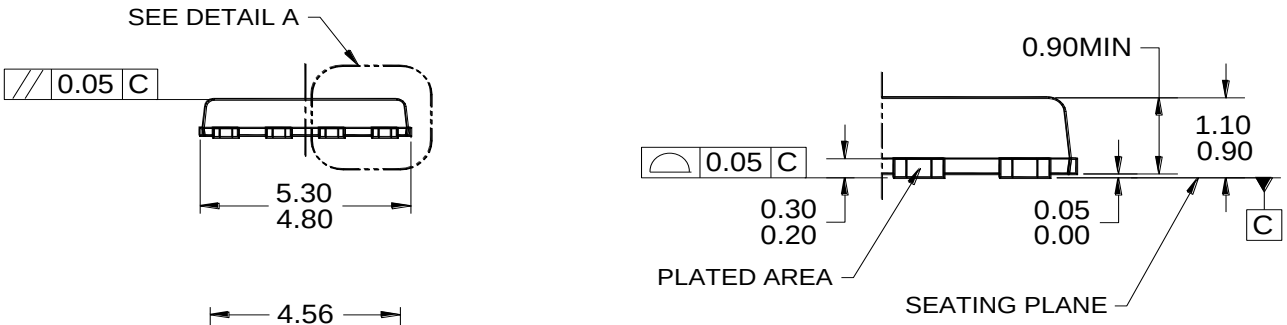
Normalized gate threshold voltage vs Temperature



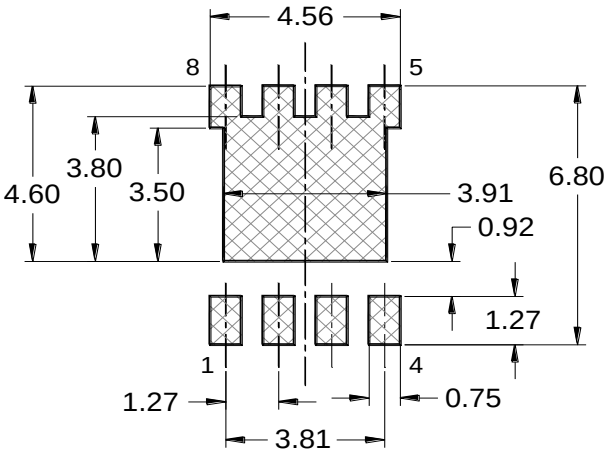
PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

PDFN56U

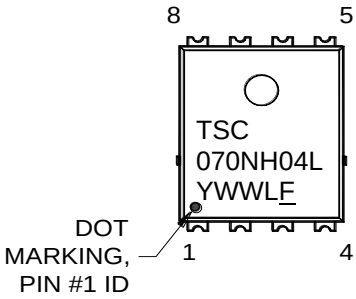




DETAIL A
(SCALE 2:1)



SUGGESTED PAD LAYOUT
(REFERENCE ONLY)



MARKING DIAGRAM

NOTES: UNLESS OTHERWISE SPECIFIED

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
3. PACKAGE OUTLINE REFERENCE: JEITA ED-7500B, EIAJ SC-111BB.
4. MOLDED PLASTIC BODY DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
5. DWG NO. REF: HQ2SD07-PDFN56U-023 REV B.

Y	=	YEAR CODE
WW	=	WEEK CODE (01~52)
L	=	LOT CODE (1~9, A~Z)
F	=	FACTORY CODE
_	=	AEC-Q101 QUALIFIED

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